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on Semiconductor® FDD86369-F085

N-Channel PowerTrench[®] MOSFET 80 V, 90 A, 7.9 m Ω

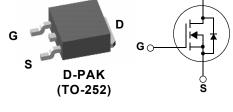
Features

- Typical $R_{DS(on)}$ = 5.9 m Ω at V_{GS} = 10V, I_D = 80 A
- Typical Q_{g(tot)} = 34 nC at V_{GS} = 10V, I_D = 80 A
- UIS Capability
- RoHS Compliant
- Qualified to AEC Q101

Applications

- Automotive Engine Control
- PowerTrain Management
- Solenoid and Motor Drivers
- Integrated Starter/Alternator
- Primary Switch for 12V Systems





FDD86369-F085 N-Channel PowerTrench[®] MOSFET

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MOSFET Maximum Ratings $T_J = 25^{\circ}C$ unless otherwise noted.

Symbol	Parameter		Ratings	Units	
V _{DSS}	Drain-to-Source Voltage		80	V	
V _{GS}	Gate-to-Source Voltage		±20	V	
	Drain Current - Continuous (V _{GS} =10) (Note 1)	T _C =25°C	90		
I _D	Pulsed Drain Current	T _C = 25°C	See Figure 4	Α	
E _{AS}	Single Pulse Avalanche Energy	(Note 2)	29	mJ	
6	Power Dissipation		150	W	
P _D	Derate Above 25°C		1.0	W/ºC	
T _J , T _{STG}	Operating and Storage Temperature		-55 to + 175	°C	
$R_{\theta JC}$	Thermal Resistance, Junction to Case		1.0	°C/W	
$R_{\theta JA}$	Maximum Thermal Resistance, Junction to Ambient	(Note 3)	52	°C/W	

Notes:

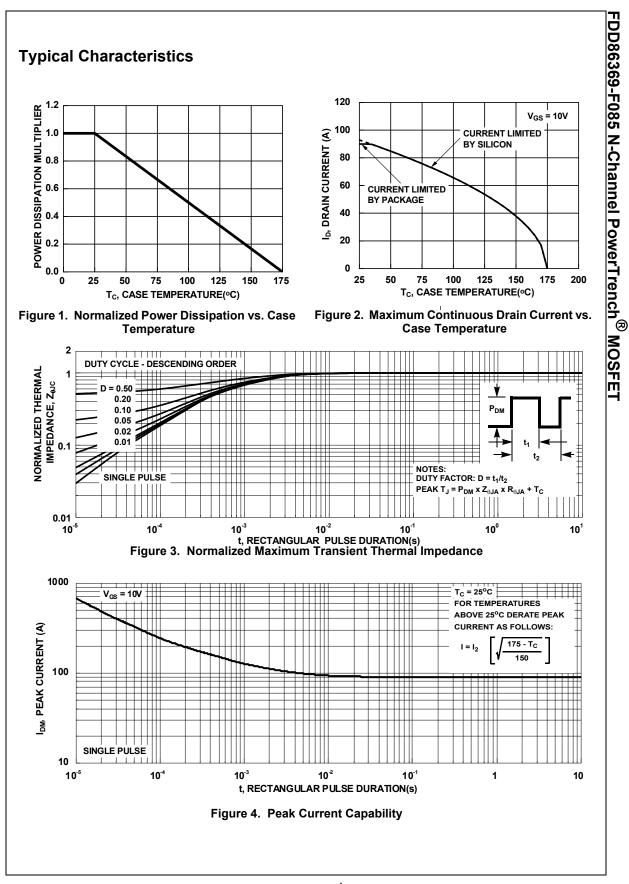
1: Current is limited by bondwire configuration.

- 2: Starting $T_J = 25^{\circ}C$, $L = 14\mu$ H, $I_{AS} = 64A$, $V_{DD} = 80V$ during inductor charging and $V_{DD} = 0V$ during time in avalanche.
- 3: R_{0JA} is the sum of the junction-to-case and case-to-ambient thermal resistance, where the case thermal reference is defined as the solder mounting surface of the drain pins. R_{0JC} is guaranteed by design, while R_{0JA} is determined by the board design. The maximum rating presented here is based on mounting on a 1 in² pad of 2oz copper.

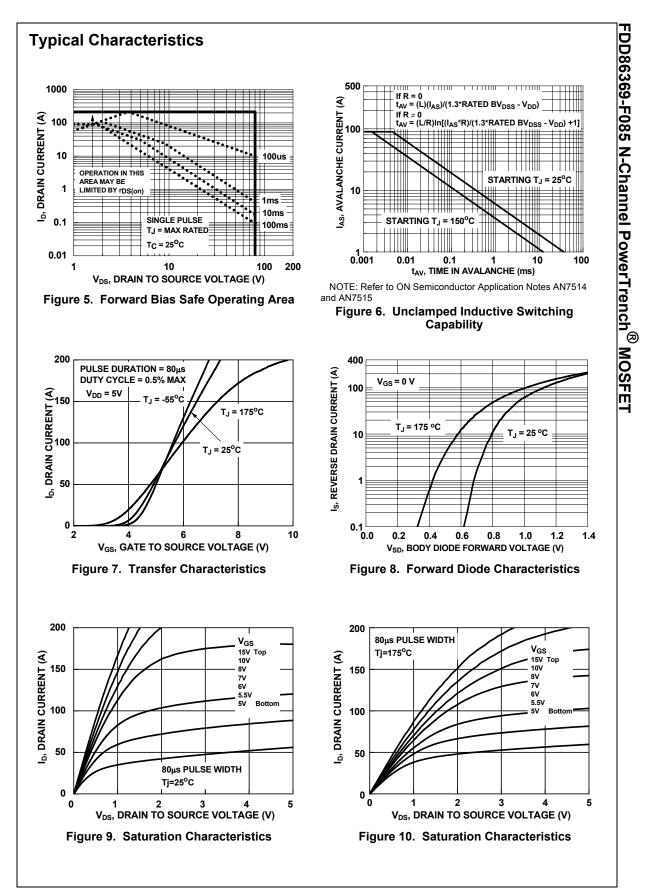
Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDD86369	FDD86369-F085	D-PAK(TO-252)	13"	16mm	2500units

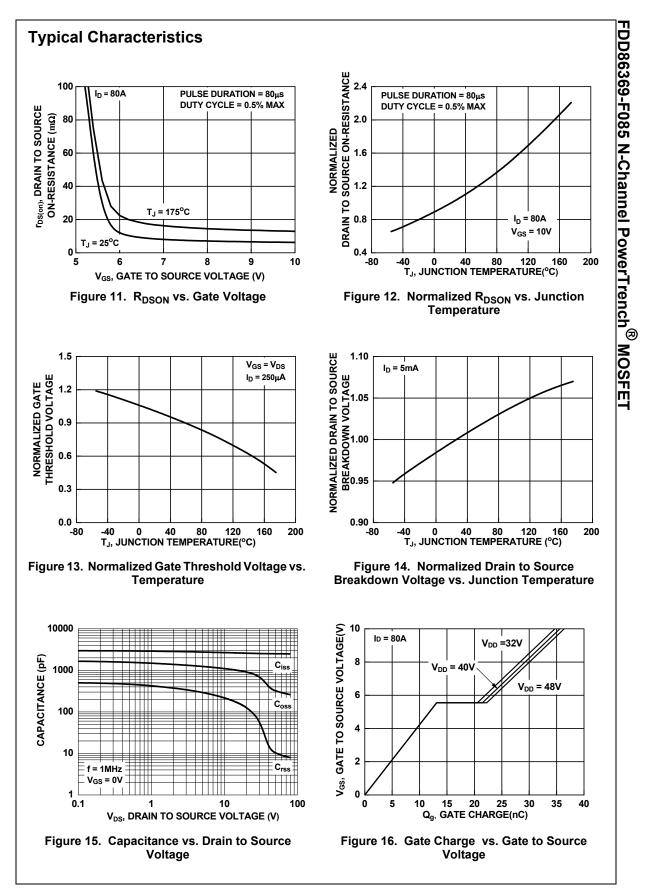
Symbol	Parameter	Test Conditions		Min.	Тур.	Max.	Units
Off Cha	racteristics						
B _{VDSS}	Drain-to-Source Breakdown Voltage	I _D = 250μA,	I _D = 250μA, V _{GS} = 0V		-	-	V
I _{DSS}	Drain-to-Source Leakage Current	$ \begin{array}{c c} V_{DS} = 80V, & T_{J} = 25^{\circ}C \\ V_{GS} = 0V & T_{J} = 175^{\circ}C \text{ (Note 4)} \\ V_{GS} = \pm 20V \end{array} $		-	-	1	μA
				-	-	1 ±100	mA nA
l _{GSS} On Cha	Gate-to-Source Leakage Current	V _{GS} – ±20V		-	-	ŦĨŨŨ	ΠA
					0 -	10	
V _{GS(th)}	Gate to Source Threshold Voltage	$V_{GS} = V_{DS},$	$T_{\rm D} = 250 \mu A$ $T_{\rm J} = 25^{\rm o} C$	2.0	2.7 5.9	4.0	V
R _{DS(on)}	Drain to Source On Resistance	I _D = 80A, V _{GS} = 10V		-	5.9	17.4	mΩ mΩ
Dynami	c Characteristics						
C _{iss}	Input Capacitance			-	2530	-	pF
C _{oss}	Output Capacitance			-	430	-	pF
C _{rss}	Reverse Transfer Capacitance			-	16	-	pF
R _g	Gate Resistance	V _{GS} = 0.5V, f = 1MHz		-	2.2	-	Ω
Q _{g(ToT)}	Total Gate Charge	$V_{GS} = 0$ to 10V $V_{DD} = 64V$		-	36	54	nC
Q _{g(th)}	Threshold Gate Charge	V_{GS} = 0 to 2	V I _D = 80A	-	4.6	-	nC
Q _{gs}	Gate-to-Source Gate Charge		_	-	13	-	nC
Q _{gd}	Gate-to-Drain "Miller" Charge			-	8.5	-	nC
Switchi	ng Characteristics						
t _{on}	Turn-On Time			-	-	70	ns
t _{d(on)}	Turn-On Delay		F	-	13	-	ns
t _r	Rise Time	V_{DD} = 40V, I _D = 80A, V_{GS} = 10V, R _{GEN} = 6Ω		-	34	-	ns
t _{d(off)}	Turn-Off Delay			-	22	-	ns
t _f	Fall Time			-	9	-	ns
t _{off}	Turn-Off Time			-	-	46	ns
Drain-S	ource Diode Characteristics						
V _{SD}	Source-to-Drain Diode Voltage	I _{SD} =80A, V _{GS} = 0V		-	-	1.25	V
		I _{SD} = 40A, \	/ _{GS} = 0V	-	-	1.2	V
t _{rr}	Reverse-Recovery Time Reverse-Recovery Charge	I _F = 80A, dl	_{SD} /dt = 100A/μs	-	49	64 53	ns
Q _{rr}		1, <u>0</u>		-	40	53	nC



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